



TS522

PRECISION LOW NOISE DUAL OPERATIONAL AMPLIFIER

- LARGE OUTPUT VOLTAGE SWING
+14.3V/-14.6V
- LOW INPUT OFFSET VOLTAGE **850 μ V max.**
- LOW VOLTAGE NOISE : **4.5nV/ $\sqrt{\text{Hz}}$**
- HIGH GAIN BANDWIDTH PRODUCT :
15MHz
- HIGH SLEW RATE : **7V/ μ s**
- LOW DISTORTION : 0.002%
- ESD INTERNAL PROTECTION 2kV
- EXCELLENT FREQUENCY STABILITY
- MACROMODEL INCLUDED IN THIS SPECIFICATION

DESCRIPTION

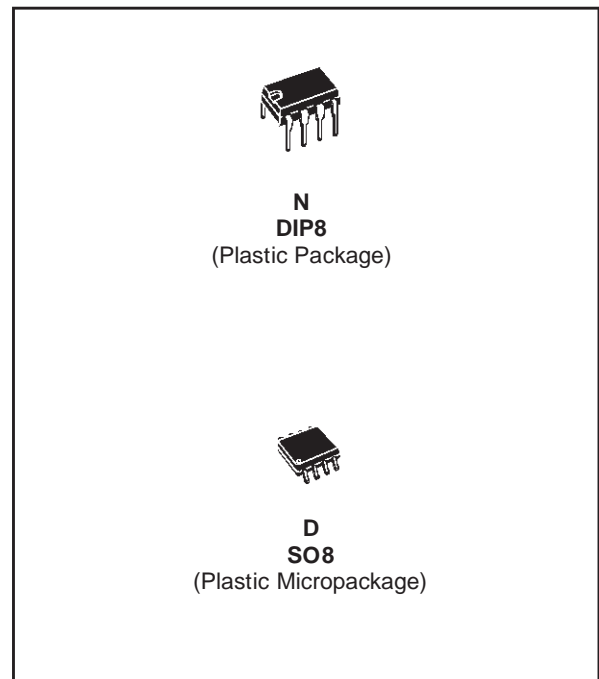
The TS522 is a monolithic dual operational amplifier mainly dedicated to audio applications. The TS522 offers a very low input offset voltage as well as low voltage noise (**4.5nV/ $\sqrt{\text{Hz}}$**) and high dynamic performances (15MHz gain bandwidth product, 7V/ μ s slew rate).

The output stage allows a large output voltage swing and symmetrical source and sink currents.

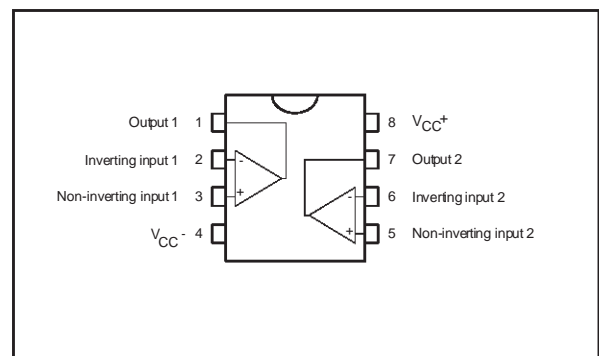
ORDER CODE

Part Number	Temperature Range	Package	
		N	D
TS522I	-40°C, +125°C	•	•

N = Dual in Line Package (DIP)
D = Small Outline Package (SO) - also available in Tape & Reel (DT)

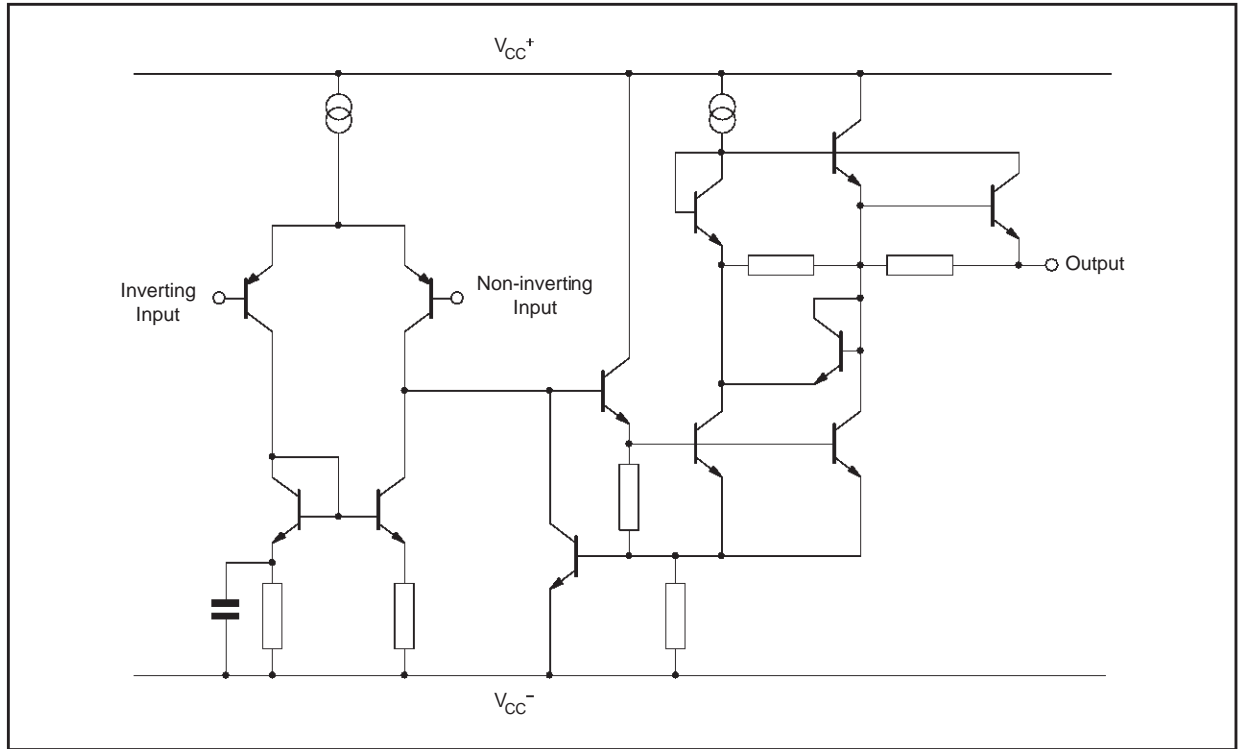


PIN CONNECTIONS (top view)



TS522

SCHEMATIC DIAGRAM (1/2 TS522)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	± 18 to 36	V
V_{id}	Differential Input Voltage ¹⁾	± 30	V
V_i	Input Voltage (see note 1)	± 15	V
	Output Short-circuit Duration ²⁾	Infinite	
T_{oper}	Operating Free-Air Temperature Range	-40 to +125	$^{\circ}\text{C}$
T_j	Maximum Junction Temperature	+ 150	$^{\circ}\text{C}$
T_{stg}	Storage Temperature Range	-65 to +150	$^{\circ}\text{C}$
P_{tot}	Maximum Power Dissipation (see note 2)	500	mW

1. Either or both input voltages must not exceed the magnitude of V_{CC}^{+} or V_{CC}^{-}
2. Power dissipation must be considered to ensure maximum junction temperature (T_j) is not exceeded

OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	± 2.5 to ± 15	V

ELECTRICAL CHARACTERISTICS
 $V_{CC}^+ = 15V, V_{CC}^- = -15V, T_{amb} = 25^\circ C$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input Offset Voltage ($V_o = 0V, V_{ic} = 0V$) $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$			0.85 1.7	mV
ΔV_{io}	Input Offset Voltage Drift $V_{ic} = 0V, V_o = 0V, T_{min} \leq T_{amb} \leq T_{max}$		2		$\mu V/^\circ C$
I_{io}	Input Offset Current ($V_{ic} = 0V, V_o = 0V$) $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$		10	150 175	nA
I_{ib}	Input Bias Current ($V_{ic} = 0V, V_o = 0V$) $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$		250	750 800	nA
V_{icm}	Common Mode Input Voltage Range ($\Delta V_{io} = 5mV, V_o = 0V$)	± 13	± 14		V
A_{vd}	Large Signal Voltage Gain ($R_L = 2k\Omega, V_o = \pm 10V$) $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$	90 85	100		dB
$\pm V_{opp}$	Output Voltage Swing ($V_{id} = \pm 1V$) $R_L = 600\Omega$ $R_L = 600\Omega$ $R_L = 2.0k\Omega$ $R_L = 2.0k\Omega$ $R_L = 10k\Omega$ $R_L = 10k\Omega$	13.2	12.2 -12.7 14 -14.2 14.3 -14.6	-13.2 -14	V
CMR	Common Mode Rejection Ratio ($V_{ic} = \pm 13V$)	80	100		dB
SVR	Supply Voltage Rejection Ratio $V_{cc}^+/V_{cc}^- = +15V/-15V$ to $+5V/-5V$	80	105		dB
I_o	Output Short Circuit Current ($V_{id} = \pm 1V$, Output to ground) Source Sink	15 20	29 37		mA
I_{cc}	Supply Current ($V_o = 0V$, All amplifiers) $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$		4	5 5.5	mA
SR	Slew Rate ($V_i = -10V$ to $+10V, R_L = 2k\Omega, C_L = 100pF, A_v = +1$)	5	7		$V/\mu s$
GBP	Gain Bandwidth Product ($f = 100kHz, R_L = 2k\Omega, C_L = 100pF$)	10	15		MHz
B	Unity Gain Bandwidth (Open loop)		9		MHz
A_m	Gain Margin ($R_L = 2k\Omega$) $C_L = 0pF$ $C_L = 100pF$		-11 -6		dB
ϕ_m	Phase Margin $C_L = 0pF$ $C_L = 100pF$		55 30		Degrees
e_n	Equivalent Input Noise Voltage ($R_s = 100\Omega, f = 1kHz$)		4.5		$\frac{nV}{\sqrt{Hz}}$
i_n	Equivalent Input Noise current ($f = 1kHz$)		0.5		$\frac{pA}{\sqrt{Hz}}$
THD	Total Harmonic Distortion $R_L = 2k\Omega, f = 20Hz$ to $20kHz, V_o = 3V_{rms}, A_v = +1$		0.002		%
V_{o1}/V_{o2}	Channel Separation ($f = 20Hz$ to $20kHz$)		120		dB
FPB	Full Power Bandwidth ($V_o = 27V_{pp}, R_L = 2k\Omega, THD \leq 1\%$)		120		kHz
Z_o	Output Impedance ($V_o = 0V, f = 9MHz$)		37		Ω
R_i	Input Resistance ($V_{ic} = 0V$)		175		$k\Omega$
C_i	Input Capacitance ($V_{ic} = 0V$)		12		pF

TS522

MACROMODEL

** Standard Linear Ics Macromodels, 1993.

** CONNECTIONS :

* 1 INVERTING INPUT

* 2 NON-INVERTING INPUT

* 3 OUTPUT

* 4 POSITIVE POWER SUPPLY

* 5 NEGATIVE POWER SUPPLY

.SUBCKT TS522 1 3 2 4 5 (analog)

.MODEL MDTH D IS=1E-8 KF=2.286238E-16
CJO=10F

* INPUT STAGE

CIP 2 5 1.200000E-11

CIN 1 5 1.200000E-11

EIP 10 5 2 5 1

EIN 16 5 1 5 1

RIP 10 11 2.363636E+00

RIN 15 16 2.363636E+00

RIS 11 15 1.224040E+01

DIP 11 12 MDTH 400E-12

DIN 15 14 MDTH 400E-12

VOFP 12 13 DC 0

VOFN 13 14 DC 0

IPOL 13 5 1.100000E-04

CPS 11 15 2.35E-09

DINN 17 13 MDTH 400E-12

VIN 17 5 1.000000E+00

DINR 15 18 MDTH 400E-12

VIP 4 18 1.000000E+00

FCP 4 5 VOFP 1.718182E+01

FCN 5 4 VOFN 1.718182E+01

FIBP 2 5 VOFN 4.545455E-03

FIBN 5 1 VOFP 4.545455E-03

* AMPLIFYING STAGE

FIP 5 19 VOFP 9.545455E+02

FIN 5 19 VOFN 9.545455E+02

CC 19 29 1.500000E-08

HZTP 30 29 VOFP 1.523529E+02

HZTN 5 30 VOFN 1.523529E+02

DOPM 51 22 MDTH 400E-12

DONM 21 52 MDTH 400E-12

HOPM 22 28 VOUT 5.172414E+03

VIPM 28 4 1.500000E+02

HONM 21 27 VOUT 4.054054E+03

VINM 5 27 1.500000E+02

DBIDON1 19 53 MDTH 400E-12

V1 51 53 0.68

DBIDON2 54 19 MDTH 400E-12

V2 54 52 0.68

RG11 51 5 3.04E+05

RG12 51 4 3.04E+05

RG21 52 5 0.6072E+05

RG22 52 4 0.6072E+05

E1 50 40 51 0 1 E2 40 39 52 0 1

EDEC1 38 39 4 0 0.5

EDEC2 0 38 5 0 0.5

DOP 51 25 MDTH 400E-12

VOP 4 25 1.474575E+00

DON 24 52 MDTH 400E-12

VON 24 5 1.474575E+00

RAJUS 50 5 1E12

GCOMP 5 4 4 5 8.1566068E-04

RPM1 5 80 1E+06

RPM2 4 80 1E+06

GAVPH 5 82 50 80 3.26E-03

RAVPHGH 82 4 613

RAVPHGB 82 5 613

RAVPHDH 82 83 1000

RAVPHDB 82 84 1000

CAVPHH 4 83 0.159E-09

CAVPHB 5 84 0.159E-09

EOUT 26 23 82 5 1

VOUT 23 5 0

ROUT 26 3 4.780354E+01

COUT 3 5 1.000000E-12

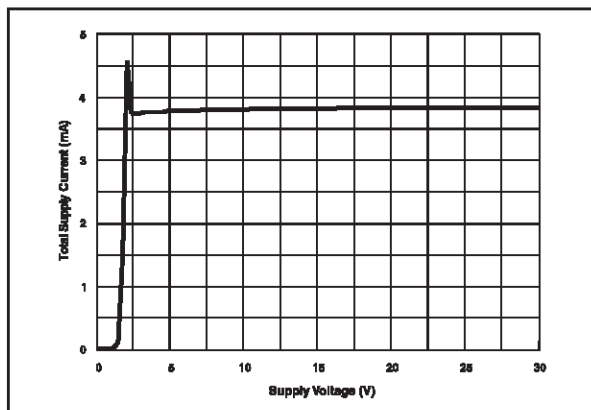
.ENDS

ELECTRICAL CHARACTERISTICS

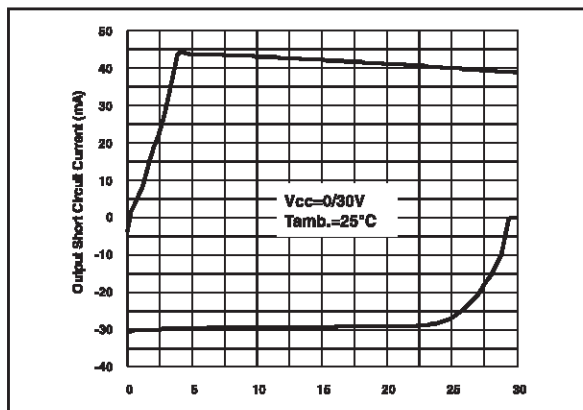
$V_{CC} = \pm 15V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

Symbol	Conditions	Value	Unit
V_{io}		0	mV
A_{vd}	$R_L = 2k\Omega$, $V_o = \pm 10V$	100	dB
I_{cc}	No load, per operator	2	mA
V_{icm}	$\Delta V_{io} = 5mV$, $V_o = 0V$	28	V
V_{opp}	$R_L = 2k\Omega$	28.2	V
I_{sink}	$V_o = 0V$	37	mA
I_{source}	$V_o = 0V$	29	mA
GBP	$R_L = 2k\Omega$, $C_L = 100pF$	15	MHz
SR	$R_L = 2k\Omega$, $C_L = 100pF$	7	V/ μs
ϕ_m	$R_L = 2k\Omega$, $C_L = 0pF$	55	Degrees

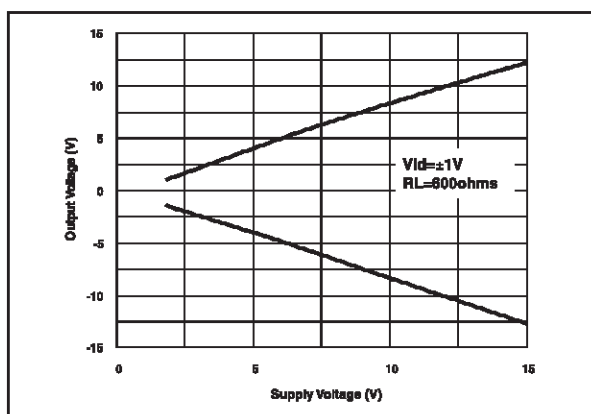
TOTAL SUPPLY CURRENT vs SUPPLY VOLTAGE



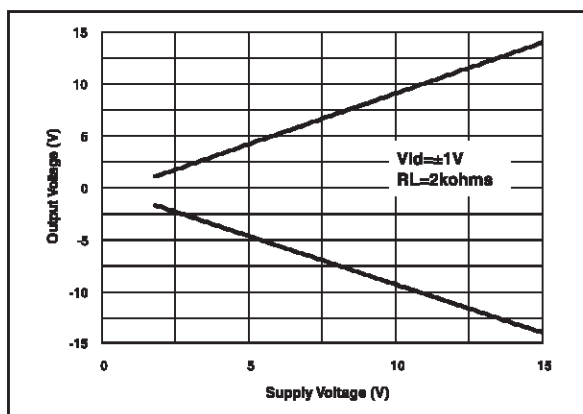
OUTPUT SHORT CIRCUIT CURRENT vs OUTPUT VOLTAGE



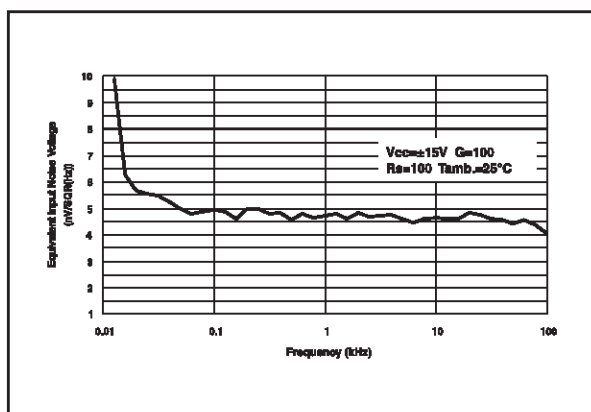
OUTPUT VOLTAGE vs SUPPLY VOLTAGE



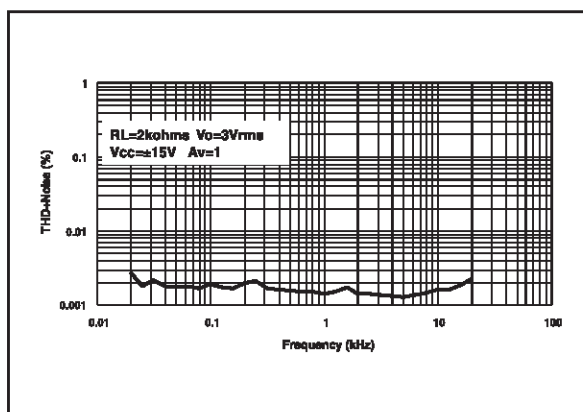
OUTPUT VOLTAGE vs SUPPLY VOLTAGE



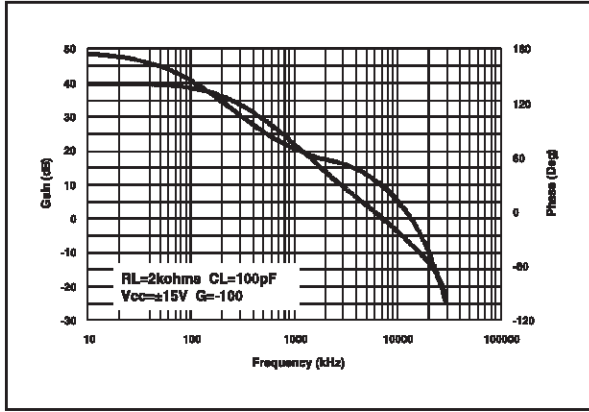
EQUIVALENT INPUT NOISE VOLTAGE vs FREQUENCY



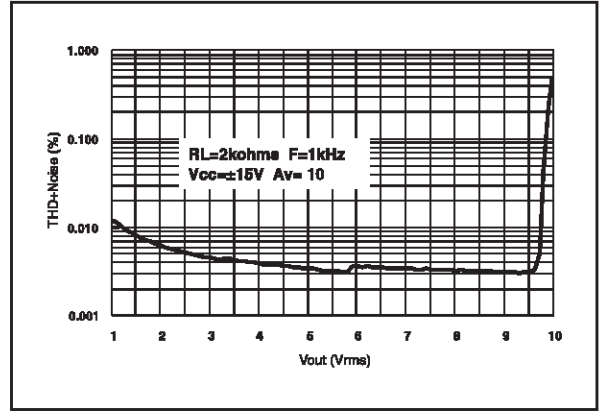
THD + NOISE vs FREQUENCY



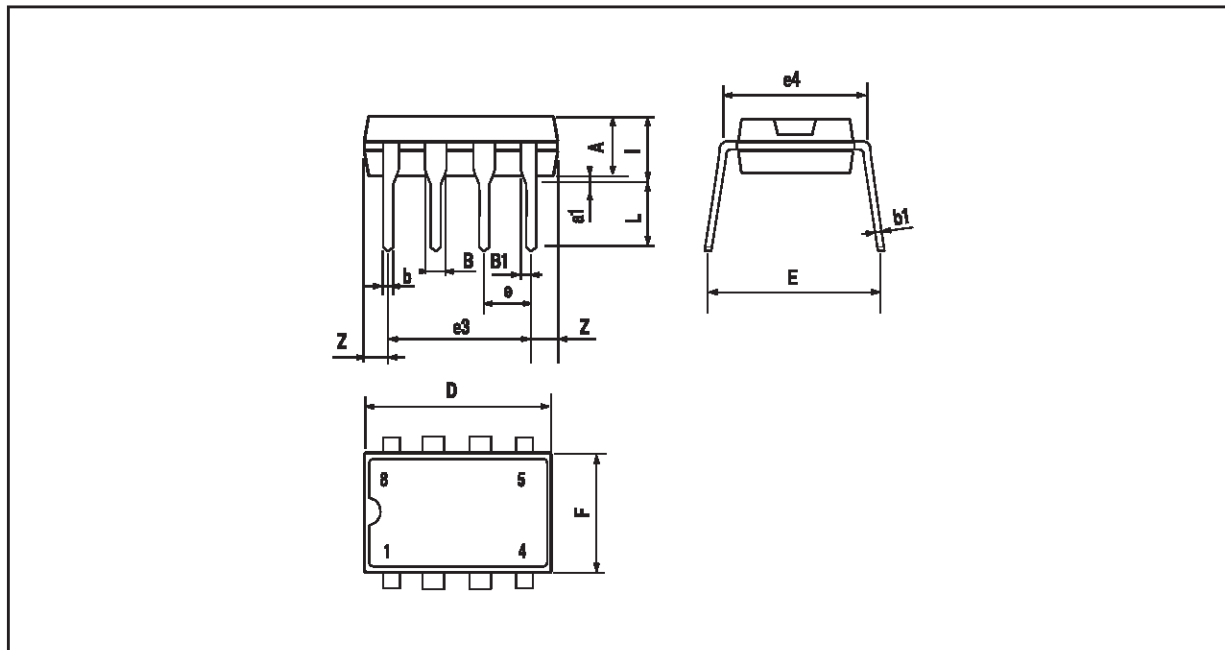
VOLTAGE GAIN AND PHASE vs FREQUENCY



THD + NOISE vs V_{out}

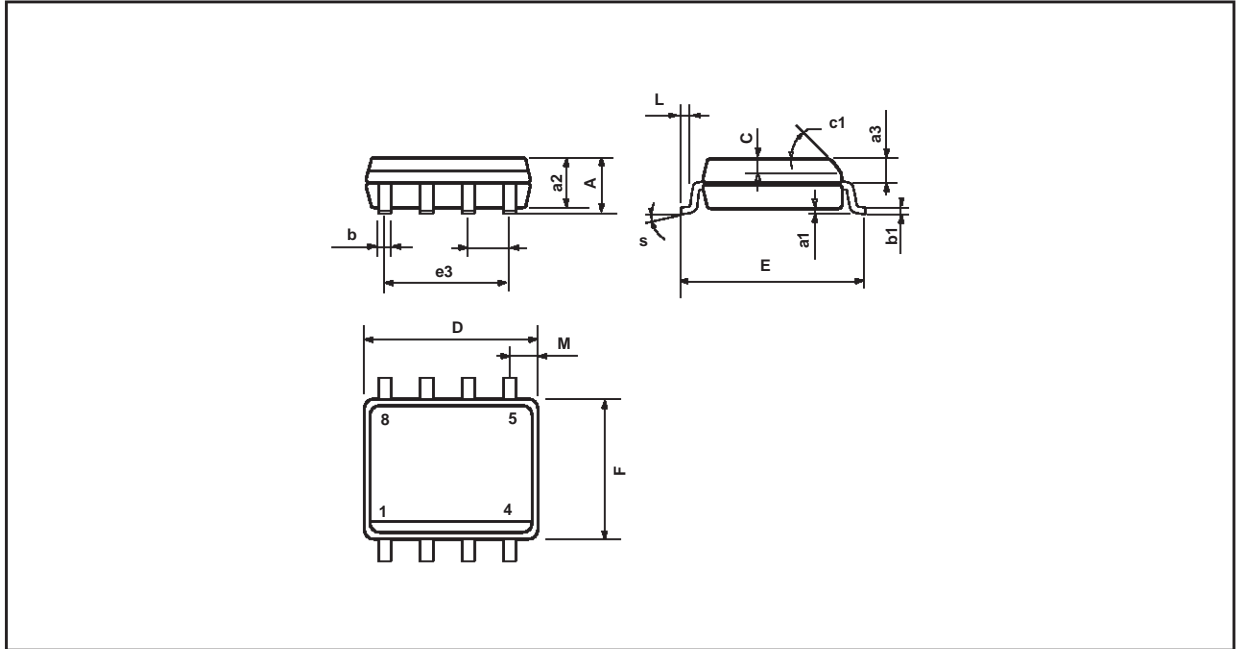


PACKAGE MECHANICAL DATA
8 PINS - PLASTIC DIP



Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A		3.32			0.131	
a1	0.51			0.020		
B	1.15		1.65	0.045		0.065
b	0.356		0.55	0.014		0.022
b1	0.204		0.304	0.008		0.012
D			10.92			0.430
E	7.95		9.75	0.313		0.384
e		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			6.6			0.260
i			5.08			0.200
L	3.18		3.81	0.125		0.150
Z			1.52			0.060

PACKAGE MECHANICAL DATA
8 PINS - PLASTIC MICROPACKAGE (SO)



Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a1	0.1		0.25	0.004		0.010
a2			1.65			0.065
a3	0.65		0.85	0.026		0.033
b	0.35		0.48	0.014		0.019
b1	0.19		0.25	0.007		0.010
C	0.25		0.5	0.010		0.020
c1	45° (typ.)					
D	4.8		5.0	0.189		0.197
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		3.81			0.150	
F	3.8		4.0	0.150		0.157
L	0.4		1.27	0.016		0.050
M			0.6			0.024
S	8° (max.)					

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